TEM Crystallography and Diffraction

Duncan Alexander EPFL-CIME

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Introduction to electron diffraction

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Why use electron diffraction?

Diffraction: constructive and destructive interference of waves

✓ wavelength of fast moving electrons much smaller than spacing of atomic planes => diffraction from atomic planes (e.g. 200 kV e^{-} , λ = 0.0025 nm)

 electrons interact very strongly with matter => strong diffraction intensity (can take patterns in seconds, unlike X-ray diffraction)

✓ spatially-localized information

(≥ 200 nm for selected-area diffraction; 2 nm possible with convergent-beam electron diffraction)

✓ close relationship to diffraction contrast in imaging

✓ orientation information

✓ immediate in the TEM!

(X diffraction from only selected set of planes in one pattern - e.g. only 2D information)

(X limited accuracy of measurement - e.g. 2-3%)

(X intensity of reflections difficult to interpret because of dynamical effects)

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Image formation



Take selected-area diffraction pattern



Basic crystallography & symmetry

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Crystals: translational periodicity & symmetry



Repetition of translated structure to infinity

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Crystallography: the unit cell

Unit cell is the smallest repeating unit of the crystal lattice Has a lattice point on each corner (and perhaps more elsewhere)

Defined by lattice parameters a, b, c along axes x, y, zand angles between crystallographic axes: $\alpha = b^{n}c$; $\beta = a^{n}c$; $\gamma = a^{n}b$



Building a crystal structure

Use example of CuZn brass Choose the unit cell - for CuZn: primitive cubic (lattice point on each corner) Choose the motif - Cu: 0, 0, 0; Zn: ½,½, Structure = lattice +motif => Start applying motif to each lattice point



Building a crystal structure

Use example of CuZn brass Choose the unit cell - for CuZn: primitive cubic (lattice point on each corner) Choose the motif - Cu: 0, 0, 0; Zn: 1/2, 1/2, Structure = lattice +motif => Start applying motif to each lattice point Extend lattice further in to space



Introduction to symmetry



Excerpt from Bruno Munari's "Zoo", First Chronical Books



Identify mirror planes

Identify rotation axis: 4-fold = defining symmetry of tetragonal lattice!





More defining symmetry elements

Hexagonal crystal system: $a = b \neq c$; $\alpha = \beta = 90^\circ$, $\gamma = 120^\circ$

Primitive cell, lattice points on each corner; view down z-axis - i.e.[1 0 0]

Draw 2 x 2 unit cells

Identify rotation axis: 6-fold (hexad) - defining symmetry of hexagonal lattice





Four possible lattice centerings



14 Bravais lattices

Combinations of crystal systems and lattice point centring that describe all possible crystals - Equivalent system/centring combinations eliminated => 14 (not $7 \times 4 = 28$) possibilities



14 Bravais lattices

Crystal System	Defining Symmetry (rotation or inversion)	Conventional Unit Cell	Conventional Lattice Types
Cubic	4 triads	$a = b = c$ $\alpha = \beta = \gamma = 90^{\circ}$	P, I, F
Hexagonal	1 hexad	$a = b \neq c$ $\alpha = \beta = 90^\circ, \gamma = 120^\circ$	Р
Trigonal	1 triad	$a = b \neq c$ $\alpha = \beta = 90^{\circ}, \gamma = 120^{\circ}$	P, R
Tetragonal	1 tetrad	$a = b \neq c$ $\alpha = \beta = \gamma = 90^{\circ}$	Р, І
Orthorhombic	3 diads	$a \neq b \neq c \alpha = \beta = \gamma = 90^{\circ}$	P, C, I, F
Monoclinic	1 diad	$a \neq b \neq c$ $\alpha = \gamma = 90^\circ, \beta \ge 90^\circ$	P, C
Triclinic	-	$a \neq b \neq c \\ \alpha \neq \beta \neq \gamma$	Р



Crystallography - lattice planes

Lattice plane is a plane which passes through any 3 lattice points which are not in a straight line

Lattice planes are described using Miller indices $(h \ k \ l)$ where the first plane away from the origin intersects the x, y, z axes at distances:





Lattice planes and symmetry

Lattice planes in a crystal related by the crystal symmetry







Electron diffraction theory



Optics: scattering from slits – video

Video: From one to many slits



Diffraction theory - 2-beam condition



2-beam condition: strong scattering from single set of planes

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Multi-beam scattering condition

Electron beam parallel to low-index crystal orientation [UVW] = zone axis Crystal "viewed down" zone axis is like diffraction grating with planes parallel to e-beam In diffraction pattern obtain spots perpendicular to plane orientation Example: primitive cubic with e-beam parallel to [0 0 1] zone axis

2×2 unit cells





Note reciprocal relationship: smaller plane spacing => larger indices $(h \ k \ l)$ & greater scattering angle on diffraction pattern from $(0 \ 0 \ 0)$ direct beam Also note Weiss Zone Law obeyed in indexing (hU + kV + IW = 0)

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Scattering from non-orthogonal crystals

With scattering from the cubic crystal we can note that the diffracted beam for plane (1 0 0) is parallel to the lattice vector [1 0 0]; makes life easy

(1 0 0) planes (1 0 0) pla

However, not true in non-orthogonal systems - e.g. hexagonal:



Basic properties of Fourier transform

• Linearity: $\begin{aligned} \mathbf{FT}\{\alpha g(x)\} &= \alpha \mathbf{FT}\{g(x)\} = \alpha G(u) \\ \mathbf{FT}\{\alpha g(x) + \beta h(x)\} &= \alpha \mathbf{FT}\{g(x)\} + \beta \mathbf{FT}\{h(x)\} = \alpha G(u) + \beta H(u) \end{aligned}$

• Shift: $FT\{g(x-a)\} = e^{-2i\pi ua}FT\{g(x)\}$ $I(u) = (e^{2i\pi ua}FT\{g(x)\}) \cdot (e^{-2i\pi ua}FT\{g(x)\}) = G^*(u) \cdot G(u)$

• Reciprocity:
$$FT{g(ax)} = \frac{1}{|a|}G(\frac{u}{a})$$

- Convolution: $FT{g(x)*h(x)} = FT{g(x)} \otimes FT{h(x)} = G(u) \otimes H(u)$
- Conservation of angle

The reciprocal lattice

In diffraction we are working in "reciprocal space"; useful to Fourier transform the crystal lattice in to a "reciprocal lattice" that represents the crystal in reciprocal (Fourier) space:







2-beam condition with one strong Bragg reflection corresponds to Ewald sphere intersecting one reciprocal lattice point

2θ

000 *G*hkl



Fourier transforms and reciprocal lattice

Real lattice is not infinite, but is bound disc of material with diameter of selected area aperture and thickness of specimen - i.e. thin disc of material







Intensity in the electron diffraction pattern



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• However, the excitation errors for the relrods change a lot, so reflection intensities also change significantly.

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Quiz: graphite \rightarrow graphene

Diffraction pattern of graphite on [0 0 1] zone axis:

What happens to relrod shape as graphite thinned \rightarrow graphene? How will this affect diffraction spot intensity for tilted sample?



Zone axis diffraction and symmetry

Zone axis SADPs have symmetry closely related to symmetry of crystal lattice Example: FCC aluminium



Symmetry quiz

- Defining symmetry of cubic material are four 3-fold rotation axes (triads) on the <1 | 1> body diagonals.
- Inversion symmetry element is combination of rotation axis with centre of symmetry (e.g. $\overline{2}, \overline{3}, \overline{6}$).
- FCC AI has space group Fm3m. If we take SADP on [1 1 1] zone axis what symmetry does ZOLZ pattern have?
- In ZOLZ lose 3rd dimension of information (i.e. have 2D projection). Therefore 3 symmetry "flattened" to give 6-fold symmetry in [1 1] SADP ⇒ loss of higher symmetry

Friedel's Law: $I_{hkl} = I_{\overline{h}\overline{k}\overline{l}}$

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Elastic scattering theory



Scattering theory - Atomic scattering factor



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Structure factor

Amplitude of a diffracted beam from a unit cell:

$$A_{\text{cell}} = \frac{e^{2\pi i \mathbf{k} \mathbf{r}}}{r} \sum_{i} f_{i}(\theta) e^{2\pi i \mathbf{K} \mathbf{r}_{i}}$$

r_{*i*}: position of each atom => **r**_{*i*}: = x_i **a** + y_i **b** + z_i **c**

K = g: **K** =
$$h a^* + k b^* + l c^*$$

Define structure factor: $F_{hkl} = \sum_{i} f_i e^{[2\pi i (hx_i + ky_i + lz_i)]}$

Intensity of reflection: $I_{hkl} \propto |A_{cell}|^2 \propto F_{hkl} \cdot F_{hkl}^*$

Note f_i is a function of **s** and $(h \ k \ l)$

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Forbidden reflections

Consider FCC lattice with lattice point coordinates: $0,0,0; \frac{1}{2}, \frac{1}{2}, 0; \frac{1}{2}, 0, \frac{1}{2}; 0, \frac{1}{2}, \frac{1}{2}$

Calculate structure factor for plane $(h \ k \ l)$ (assume single atom motif):

$$F_{hkl} = \sum_{i} f_{l} e^{[2\pi i (hx_{l}+ky_{l}+lz_{l})]}$$
where: $e^{i\theta} = \cos \theta + i \sin \theta$
For atomic structure factor f find:
$$F_{hkl} = f[1 + e^{\pi i (h+k)} + e^{\pi i (h+l)} + e^{\pi i (k+l)}]$$
Since: $e^{n\pi i} = (-1)^{n}$
For $h k l$ all even or all odd: $F_{h k l} = 4f$
For $h k l$ mixed even and odd: $F_{h k l} = 0$

$$\sum_{k \in I} f_{h k l} = 0$$
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Extinction rules

Face-centred cubic: reflections with mixed odd, even h, k, l absent:

$$F_{hkl} = f_i \Big[1 + e^{\pi i (h+k)} + e^{\pi i (h+l)} + e^{\pi i (k+l)} \Big]$$

Body-centred cubic: reflections with h + k + l = odd absent:

 $F_{hkl} = f_i \left[1 + e^{\pi i (h+k+l)} \right]$

Reciprocal lattice of FCC is BCC and vice-versa

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Theory of electron diffraction in TEM – Resources

- "Transmission Electron Microscopy" by Williams and Carter Chapters
 3, 11, 12: Derivation of Bragg and Laue equations, introduction of
 diffraction vector g, excitation error s
- "Large Angle Convervent Beam Electron Diffraction", Morniroli (electronic on-line from EPFL library), Chapters 2 and 3: Elegant pictorial way to understand electron diffraction with parallel incident beam
- JEMS Pierre Stadelmann's electron microscopy simulation software: contact Prof. Stadelmann (CIME) to use